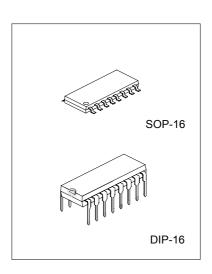
### LOW VOLTAGE TELEPHONE TRANSMISSION CIRCUIT WITH DIALLER INTERFACE

### **DESCRIPTION**

The UTC TEA1062/1062A is a bipolar integrated circuit performing all speech and line interface function, required in the fully electronic sets. It performs electronic switching telephone between dialing speech. The circuit is able to operate down to D.C. line voltage of 1.6V (with reduced performance) to facilitate the use of more telephone sets in parallel.

#### **FEATURES**

- \* Low d.c. line voltage; operates down to 1.6V (excluding polarity guard).
- \*Voltage regulator with adjustment static resistance.
- \*Provides supply with limited current for external circuitry.
- \*Symmetrical high-impedance inputs (64k $\Omega$ )for dynamic, magnetic or piezoelectric microphones.
- \*Asymmetrical high-impedance inputs (32k $\Omega$ )for electret microphones.
- \*DTMF signal input with confidence tone.



- \*Mute input for pulse or DTMF dialing.
- \*Receivering amplifier for several types of earphones.
- \*Large amplification setting range on microphone and earpiece amplifiers.
- \*Line loss compensation facility, line current depedant (microphone and earpiece amplifiers).
- \*Gain control adaptable to exchange supply.
- \*Possibility to adjust the d.c. line voltage.

### QUICK REFERENCE DATA

Line voltage at line=15mA	VLN	typ. 3.8 V
Line current operating range[pin1]		
normal operation	line	11 to 140 mA
with reduced performance	lline	1 to 11 mA
Internal supply current	Icc	typ. 1mA
Supply current for peripherials		
at Iline=15 mA MUTE input LOW(1062 is HIGH)		
VCC>2.2V	lp	typ. 1.8mA
VCC>2.8V	lp	typ. 0.7mA
Voltage amplification range		
microphone amplifier	Avd	44 to 52 dB
receiving amplififer	Avd	20 to 39 dB
Line loss compansation		
Amplification control range	Avd	typ. 6 dB
Exchange supply voltage range	Vexch	36 to 60V
Exchange feeding bridge resistance range	Rexch	400 to 1000 Ω
Operating ambient temperature range	Tamb	-25 to +75°C

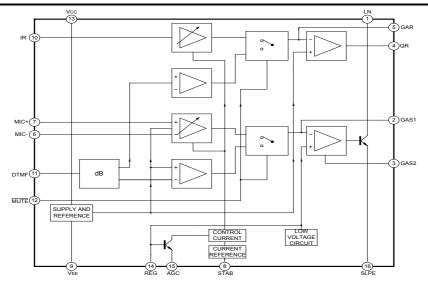


Fig.1 Block Diagram

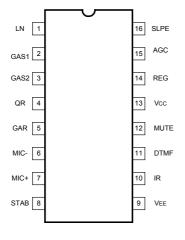


Fig.2 PIN CONFIGURATIONS

1	LN	positive line terminal
2	GAS1	gain adjustment; transmitting amplifier
3	GAS2	gain adjustment; transmitting amplifier
4	QR	non-inverting output, receiving amplifier
5	GAR	gain adjustment; receiving amplifier
6	MIC-	inverting microphone input
7	MIC+	on-inverting microphone input
8	STAB	current stabilizer
9	VEE	negative line terminal
10	IR	receiving amplifier input
11	DTMF	dual-tone multi-frequency input
12	MUTE	mute input
13	Vcc	positive supply decoupling
14	REG	voltage regulator decoupling
15	AGC	automatic gain control input
16	SLPE	slope (DC resistance) adjustment

#### ABSOLUTE MAXIMUM RATINGS

TEST CONDITIONS	SYMBOL	MIN	MAX	UNIT
	VLN		12	V
	VLN		13.2	V
R10=13Ω				
R9=20Ω				
(see Fig.15)	VLN		28	V
R9=20Ω	Iline		140	mA
	Vi		VCC+0.7	V
	-Vi		0.7	V
R9=20Ω	Ptot		640	mW
	Tstg	-40	+125	°C
	Tamb	-25	+75	°C
	Tj		+125	°C
	R10=13 $\Omega$ R9=20 $\Omega$ (see Fig.15) R9=20 $\Omega$	$\begin{array}{c c} & VLN \\ & VLN \\ \hline & R10=13\Omega \\ R9=20\Omega \\ (see Fig.15) & VLN \\ R9=20\Omega & Iline \\ & Vi \\ & -Vi \\ \hline & R9=20\Omega & Ptot \\ \hline & Tstg \\ \hline \end{array}$	$\begin{array}{c cccc} & & & & & & & & \\ & & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & $	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

- 1. Mostly dependent on the maximum required Tamb and the voltage between LN and SLPE (see Figs 6).
- 2. Calculated for the maximum ambient temperature specified Tamb=75°C and a maximum junction temperature of 125°C.

### THERMAL RESISTANCE

From junction to ambient in free air Rth j-a = 75K/W

ELECTRICAL CHARACTERISTICS(Iline=11 to 140mA;VEE=0V;f=800Hz;Tamb=25°C; unless otherwise specified)

opeomea)						
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Supply; LN and VCC(pins 1 and 1	(3)					
Voltage Drop Over Circuit,						
between LN and VEE	MIC inputs open					
	Iline=1mA	VLN		1.6		V
	lline=4mA	VLN		1.9		V
	Iline=15mA	VLN	3.55	4.0	4.25	V
	Iline=100mA	VLN	4.9	5.7	6.5	V
	Iline=140mA	VLN			7.5	V
Variation with Temperature	lline=15mA	ΔVLN/ΔΤ		-0.3		mV/K
Voltage Drop Over Circuit,						
between LN and VEE with	Iline=15mA					
External Resistor Rva	RVA(LN to REG)			3.5		V
	=68kΩ					
	Iline=15mA					
	RVA(REG to SLPE)			4.5		V
	=39kΩ					
Supply Current	Vcc=2.8V	Icc		0.9	1.35	mA
Supply Voltage Available for						
Peripheral Circuitry	line=15mA					
TEA1062	Ip=1.2mA;MUTE=HIGH	Vcc	2.2	2.7		V
	lp=0mA;MUTE=HIGH	Vcc		3.4		V
TEA1062A	Ip=1.2mA;MUTE=LOW	Vcc	2.2	2.7		V
	Ip=0mA;MUTE=LOW	Vcc		3.4		V

### ELECTRICAL CHARACTERISTICS (continued)

ELECTRICAL CHARACTERIS	J 1 100 (continued)					
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Microphone inputs MIC+ and MIC- (p	ins 6 and 7)					
Input impedance (differential)						
between MIC- and MIC+		Zi		64		kΩ
Input impedance (sigle-ended)						
MIC- or MIC+ to VEE		<b>Z</b> i		32		kΩ
Common Mode Rejection Ratio		kcmr		82		dB
Voltage Gain						
MIC+ or MIC- to LN	Iline=15mA					
	R7=68kΩ	Gv	50.5	52.0	53.5	dB
Gain Variation with Frequency						
at f=300Hz and f=3400Hz	w.r.t.800Hz	$\Delta G$ vf		+-0.2		dB
Gain Variation with Temperature						
at -25°C and +75°C	w.r.t.25°C					
	without R6;					
	Iline=50mA	$\Delta G$ vT		+-0.2		dB
Dual-tone multi-frequency input DTMF	(pin 11)					
Input impedance		Zi		20.7		kΩ
Voltage Gain from DTMF to LN	Iline=15mA					
	R7=68kΩ	Gv	24	25.5	27	dB
Gain Variation with Frequency						
at f=300Hz and f=3400Hz	w.r.t.800Hz	$\Delta G$ vf		+-0.2		dB
Gain Variation with Temperature						
at -25°C and +75°C	w.r.t.25°C					
	Iline=50mA	$\Delta G$ vT		+-0.2		dB
Gain Adjustment GAS1 and GAS2 (p	ins 2 and 3)					
Gain Variation of the Transmitting						
Amplifier by Varying R7 between						
GAS1 and GAS2		$\Delta G_V$	-8		0	dB
Sending Amplifier Output LN(pin 1)						
Output Voltage	Iline=15mA					
	THD=10%	VLN(rms)	1.7	2.3		V
	Iline=4mA	, ,				
	THD=10%	VLN(rms)		0.8		V
Noise output voltage	Iline=15mA;					
	R7=68kΩ;					
	200Ω between					
	MIC- and MIC+;					
	psophometrically					
	weighted	VNO(rms)		-69		dBmp
Receiving Amplifier Input IR (pin 10)						
Input impedance		Zi		21		kΩ
Receiving Amplifier Output QR (pin 4	.)	*	•			•
Output Impedance		Zo		4		Ω
Voltage gain from IR to QR	Iline=15mA;					
	RL(from pin 9 to					
	pin 4 )=300Ω	Gv	29.5	31	32.5	dB

### ELECTRICAL CHARACTERISTICS (continued)

ELECTRICAL CHARACTERIS	STICS (continued)					
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Gain Variation with Frequency						
at f=300Hz and f=3400Hz	w.r.t.800Hz	$\Delta Gvf$		$\pm 0.2$		dB
Gain Variation with Temperature						
at-25°C and +75°C	w.r.t.25°C					
	without R6					
	Iline=50mA	$\Delta G$ vT		+-0.2		dB
Output Voltage	sinwave drive;					
	Ip=0mA;THD=2%					
	R4=100kΩ					
	Iline=15mA					
	RL=150Ω	Vo(rms)	0.22	0.33		V
	RL=450Ω	Vo(rms)	0.3	0.48		V
Output Voltage	THD=10%					
	R4=100kΩ					
	RL=150Ω					
	Iline=4mA	Vo(rms)		15		mV
Noise Output Voltage	Iline=15mA					
	R4=100kΩ					
	IR open-circuit					
	psophometrically					
	weighted					
	RL=300Ω	VNO(rms)		50		μV
Gain adjustment GAR (pin 5)						
Gain Variation of Receiving						
Amplifier Achievable by						
Varying		$\Delta Gv$	-11		0	dB
R4 between GAR and QR						
Mute Input (pin 12)						
Input Voltage(HIGH)		VIH	1.5		Vcc	V
Input Voltage(LOW)		VIL			0.3	V
Input Current		Імите		8	15	μΑ
Reduction of Gain		•			•	
MIC+ or MIC- to QR	MUTE=LOW	ΔGv		70		dB
Voltage Gain from DTMF to QR	MUTE=LOW					
	R4=100kΩ					
	RL=300Ω	Gv		-19		dB
Automatic Gain Control Input AGC				•	•	
Controlling the Gain from IR to QR						
and the Gain from MIC+/MIC-						
to LN;R6 between AGC and VEE	R6=110kΩ					
Gain Control Range	lline=70mA	ΔGv		-5.8		dB
Highest Line Current	, . <del>.</del>					
for Maximum Gain		lline		23		mA
Minimum Line Current						(
for Minimum Gain		lline		61		mA
101 William Calif	l	IIIIIE	l	01		111/7

#### **FUNCTIONAL DESCRIPTION**

### Supply: VCC, LN, SLPE, REG and STAB

Power for the UTC TEA1062/1062A and its peripheral circuits is usually obtained from the telephone line. The IC supply voltage is derived from the line via a dropping resistor and regulated by the UTC TEA1062/1062A,The supply voltage Vcc may also be used to supply external circuits e.g. dialling and control circuits. Decoupling of the supply voltage is performed by a capacitor between Vcc and VEE while the internal voltage regulator is decoupled by a capacitor between REG and VEE. The DC current drawn by the device will vary in accordance with varying values of the exchange voltage(Vexch), the feeding bridge resistance(Rexch) and the DC resistance the telephone line(Rline). The UTC TEA1062/1062A has an internal current stabilizer operating at a level determined by a  $3.6k\,\Omega$  resistor connected between STAB and VEE( see Fig.8). When the line current(line) is more than 0.5 mA greater than the sum of the IC supply current (Icc) and the current drawn by the peripheral circuitry connected to VCC(Ip) the excess current is shunted to VEE via LN. The regulated voltage on the line terminal(VLN) can be calculated as:

VLN=Vref+ISLPE\*R9 or;

VLN=Vref+[(Iline – ICC - 0.5\*10<sup>-3</sup>A)-Ip]\*R9

where:Vref is an internally generated temperature compensated reference voltage of 3.7V and R9 is an external resistor connected between SLPE and VEE. In normal use the value of R9 would be  $20\Omega$ . Changing the value of R9 will also affect microphone gain, DTMF gain,gain control characteristics, side tone level, maxmimum output swing on LN and the DC characteristics (especially at the lower voltages). Under normal conditions, when ISLPE>=ICC+0.5mA +lp, the static behaviour of the circuit is that of a 3.7V regulator diode with an internal resistance equal to that of R9.In the audio frequency range the dynamic impedance is largely determined by R1.Fig.3 shows the equivalent impedance of the circuit.

### Microphone inputs(MIC+ and MIC-) and gain pins (GAS1 and GAS2)

The UTC TEA1062/1062A has symmetrical inputs. Its input impedance is  $64k\Omega$  (2\*32k $\Omega$ ) and its voltage gain is typically 52 dB (when R7=68kΩ.see Fig.13). Dynamic, magnetic, piezoelectric or electret (with built-in FET source followers) can be used. Microphone arrangements are illustrated in Fig.10. The gain of the

microphone amplifier can be adjusted between 44dB and 52dB to suit the sensitivity of the transducer in use. The gain is proportional to the value of R7 which is connected between GAS1 and GAS2. Stability is ensured by the external capacitors, C6 connected between GAS1 and SLPE and C8 connected between GAS1 and VEE. The value of C6 is 100pF but this may be increased to obtain a first-order low-pass filter. The value of C8 is 10 times the value of C6. The cut-off frequency corresponds to the time constant R7\*C6.

### Mute input (MUTE)

A LOW(UTC TEA1062 is HIGH) level at MUTE enables DTMF input and inhibites the microphone inputs and the receiving amplifier inputs; a HIGH(UTC TEA1062 is LOW) level or an open circuit does the reverse. Switching the mute input will cause negligible clickis at the telephone outputs and on the line. In case the line current drops below 6mA(parallal opration of more sets) the circuit is always in speech condition independant of the DC level applied to the MUTE input.

#### Dual-tone multi-frequency input (DTMF)

When the DTMF input is enabled dialling tones may be sent onto the line. The voltage gain from DTMF to LN is typically 25.5dB(when R7=68kΩ) and varies with R7 in the same way as the microphone gain. The signalling tones can be heard in the earpiece at a low level(confidence tone).

### Receiving amplifier (IR,QR and GAR)

The receiving amplifier has one input (IR) and a non-inverting output (QR). Earpiece arrangements are illustrated in Fig.11. The IR to QR gain is typically 31dB (when R4=100k $\Omega$ ). It can be adjusted between 20 and 31dB to match the sensitivity of the transducer in use. The gain is set with the value of R4 which is connected between GAR and QR.The overall receive gain, between LN and QR, is calculated by substracting the anti-sidetone network attenuation (32dB) from the amplifier gain. Two external capacitors, C4 and C7, ensure stability. C4 is normally 100pF and C7 is 10 times the value of C4. The value of C4 may be increased to obtain a first-order low-pass filter. The cut-off frequency will depend on the time constant R4\*C4. The output voltage of the receiving amplifier is specified for continuous-wave drive. The maximum output voltage will be higher under speech conditions where the peak to RMS ratio is higher.

#### Automatic gain control input(AGC)

Automatic line loss compensation is achieved by connecting a resistor(R6) between AGC and VEE. The automatic gain control varies the gain of the microphone amplifier and the receiving amplifier in accordance with the DC line current. The control range is 5 8dB which corresponds to a line length of 5km for a 0.5mm diameter twisted pair copper cable with a DC resistance of  $176\Omega/km$  and average attenuation of 1.2dB/km. Resistor R6 should be chosen inaccordance with the exchange supply voltage and its feeding bridge resistance(see Fig.12 and Table 1). The ratio of start and stop currents of the AGC curve is independent of the value of R6. If no automatic line loss compensation is required the AGC may be left open-circuit. The amplifier, in this condition, will give their maximum specified gain.

#### Side-tone suppression

The anti-sidetone network, R1//Zline, R2, R3, R8, R9 and Zbal,(see Fig.4) suppresses the transmitted signal in the earpiece. Compensation is maximum when the following conditions are fulfilled:

- (a) R9\*R2=R1[R3+(R8//Zbal)];
- (b) [Zbal/(Zbal+R8)]=[Zline/(Zline+R1)];

If fixed values are chosen for R1, R2, R3 and R9 then condition(a) will always be fullfilled when R8/Zball R3. To obtain optimum side-tone suppression condition(b) has to be fulfilled which results in:

 $Z_{bal}=(R8/R1)$   $Z_{line}=k^*Z_{line}$  where k is a scale factor; K=(R8/R1).

The scale factor (k), dependent on the value of R8, is chosen to meet following criteria:

- (a) Compatibility with a standard capacitor from the E6 or E12 range for Zbal,
- (b) | Zbal//R8 | 《R3 fulfilling condition (a) and thus ensuring correct anti-sidetone bridge operation,
- (c) | Zbal+R8 | » R9 to avoid influencing the transmitter gain.

In practice  $Z_{\text{line}}$  varies considerably with the type and length. The value chosen for  $Z_{\text{bal}}$  should therefore be for an average line length thus giving optimum setting for short or long lines.

#### Example

The balance impedance Z<sub>bal</sub> at which the optimum suppression is present can be calculated by: Suppose Z<sub>line</sub> =  $210\Omega+(1265\Omega//140nF)$  representing a 5km line

of 0.5 mm diameter, copper, twisted pair cable matched to  $600\Omega(176\Omega/\text{km};38\text{nF/km})$ . When k=0.64 then R8=390 $\Omega$ , Zbal=130 $\Omega$ +(820 $\Omega$ //220nF). At line currents below 9mA the internal reference voltage is automatically adjusted to a lower value(typically 1.6V at 1mA) This means that more sets can be operated in parallel with DC line voltages (excluding the polarity guard) down to an absolute minimum voltage of 1.6V. With line currents below 9mA the circuit has limited sending and receiving levels. The internal reference voltage can be adjusted by means of an external resistor(RVA). This resistor when connected between LN and REG will decrease the internal reference voltage and when connected between REG and SLPE will increase the internal reference voltage. Current(Ip) available from Vcc for peripheral circuits depends on the external components used. Fig.9 shows this current for Vcc > 2.2V. If MUTE is LOW (1062 is HIGH)when the receiving amplifier is driven the available current is further reduced. Current availability can be increased by connecting the supply IC(1081) in parallel with R1, as shown in Fig.16(c), or, by increasing the DC line voltage by means of an external resistor(RvA) connected between REG and SLPE.

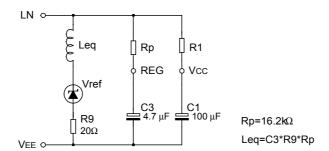


Fig.3 Equivalent impedance circuit

The anti-sidetone network for the UTCTEA1062/1062A family shown in Fig.4 attenuates the signI received from the line by 32 dB before it enters the receiving amplifier. The attenuation is almost constant over the whole audio frequency range. Fig.5 shows a convertional Wheatstone bridge anti-sidetone circuit that can be used as an alternative. Both bridge types can be used with either resistive or complex set impedances.

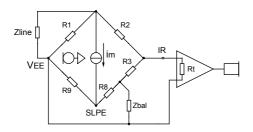


Fig 4 Equivalent circuit of UTC TEA1062/1062A anti-sidetone bridge

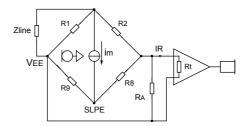


Fig 5 Equivalent circuit of an anti-sidetone network in a wheatstone bridge configuration

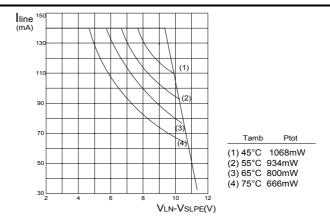


Fig.6 UTC TEA1062/ TEA1062A safe operating area

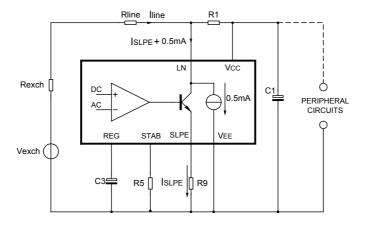
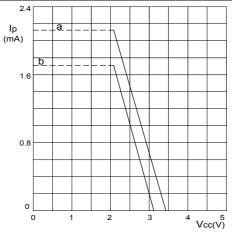


Fig.8 Supply arrangement

#### LINEAR INTEGRATED CIRCUIT UTC TEA1062/1062A



(a) Ip=2.1mA (b) lp=1.7mA Iline=15mA at VLN=4V R1=620 $\Omega$  and R9=20 $\Omega$ 

Fig.9 Typical current Ip available from Vcc peripheral circuitry with Vcc>=2.2V.

curve (a) is valid when the receiving amplifier is not driven or when MUTE =LOW(UTC TEA1062 is HIGH) .curve(b) is valid when MUTE=HIGH(UTC TEA1062 is LOW) and the receiving amplifier is driven; Vo(rms) = 150 mV,  $RL = 150 \Omega$ . The supply possibilities can be increased simply by setting the voltage drop over the circuit VLN to a high value by means of resistor RVA connected between REG and SLPE.

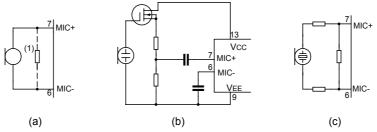


Fig. 10 Alternative microphone arrangement

- (a) Magnetic or dynamic microphone. The resistor marked(1) may be connected to decrease the terminating impedance.
- (b) Electret microphone.
- (c) Piezoelectric microphone.

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#### LINEAR INTEGRATED CIRCUIT UTC TEA1062/1062A

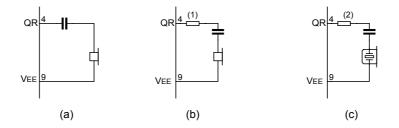
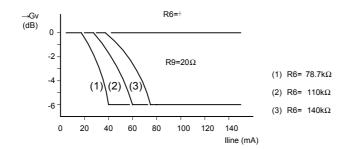


Fig.11 Alternative receiver arrangement

- (a) Dynamic earpiece.
- (b) Magnetic earpiece. The resistor marked(1) may be connected to prvent distortion (inductive load)
- (c) Piezoelectric earpiece. The earpiece marked(2) is requirred to increase the phase margin (capacitive load) Fig.12 Variation of gain with line urrent, with R6 as a parameter.



		$Rexch(\Omega)$			
		400	600	800	1000
		$R6(k\Omega)$			
	36	100	78.7	×	×
Vexch(V)	48	140	110	93.1	82
	60	×	×	120	102

Table 1 Values of resistor R6 for optimum line loss compensation, for various usual values of exchange supply vloltage(Vexch) and exchange feeding bridge resistance(Rexch);R9=20Ω.

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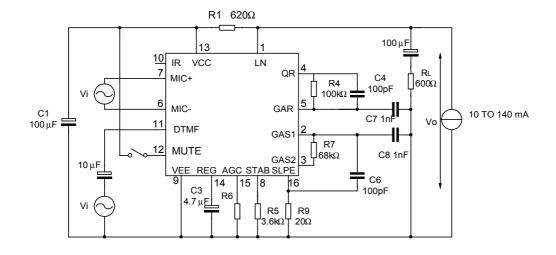


Fig.13 Test circuit defining voltage gain of MIC+,MIC- and DTMF inputs.

Voltage gain is defined as: GV=20\*log(|VO/Vi|).For measuring the gain from MIC+ and MIC- the MUTE input should be HIGH(UTC TEA1062 is LOW) or open-circuit, for measuring the DTMF input MUTE should be LOW(UTC TEA1062 is HIGH). Inputs not under test should be open-circuit.

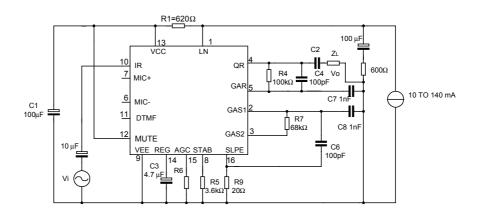


Fig.14 Test circuit for defining voltage gain of the receiving amplifier. Voltage gain is defined as: GV=20\*log(|VO/Vi|).

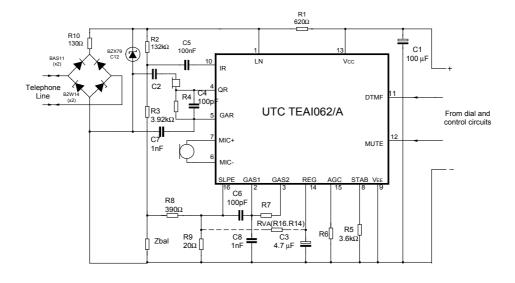
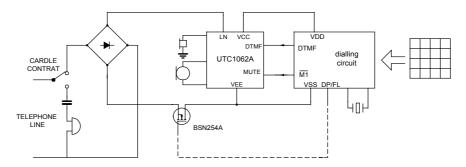


Fig.15 Typical application of the UTC TEA1062A ,shown here with a piezoelectric earpiece and DTMF dialling. The bridge to the left ,the Zener diode and R10 limit the current into the circuit and the voltage across the circuit during line transients. Pulse dialling or register recall required a different protection arrangement. The DC line voltage can be set to a higher value by resistor RVA(REG to SLPE).



Typical applications of the UTC TEA1062/1062A (simplified) The dashed lines show an optional flash ( register recall by timed loop break).